SANKEN ELECTRIC

SJPB-H6

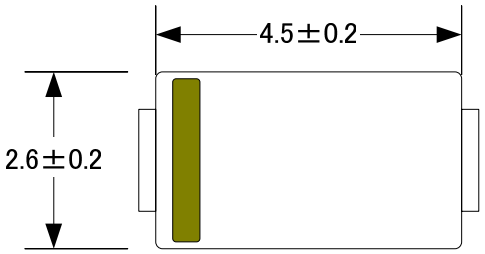
Schottky Barrier Rectifier

Mar. 2008

General Description

SJPB-H6 is a Schottky Barrier Diode, and has achieved low leakage current and low VF by selecting the best barrier metal.

Package



Applications

- DC-DC converters
- AC adapter
- High frequency rectification circuit

Features

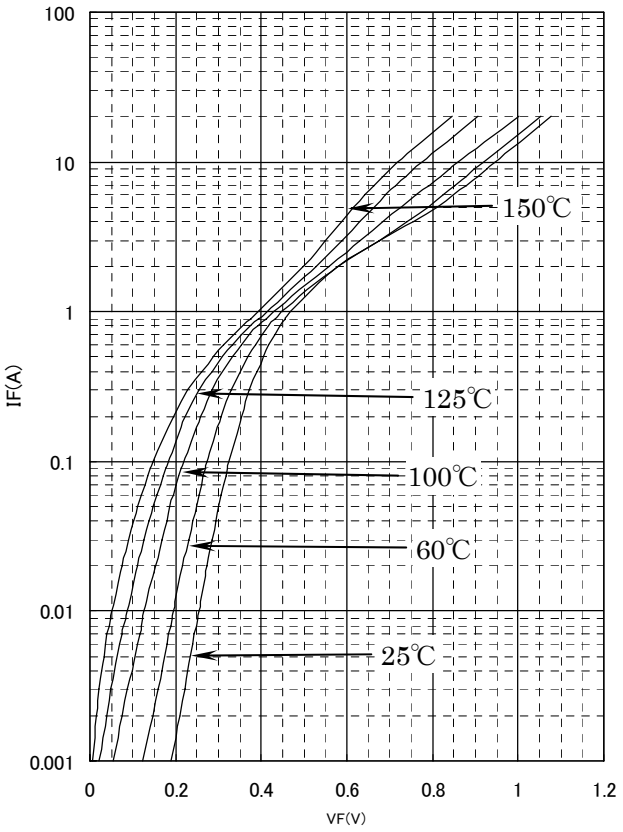
- Super-high speed & low noise switching.
- Low forward voltage drop.

Key Specifications

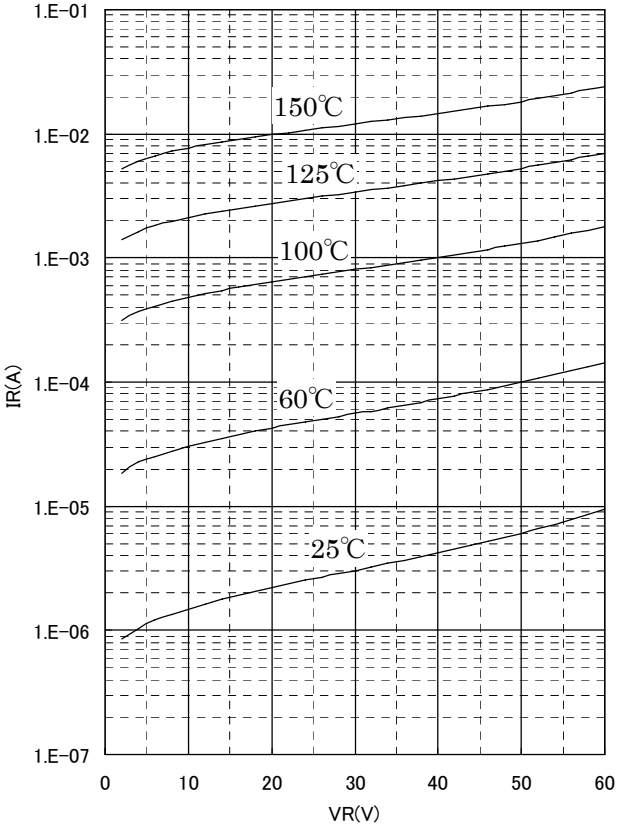
Symbol	Unit	Rating	Conditions
V_{RM}	V	60	
V_F	V	0.69	I_F=2.0A
$I_{F(AV)}$	A	2.0	

Typical Characteristics

SJPB-H6 IF-VF Characteristics



SJPB-H6 VR-IR Characteristics



✶ **Absolute maximum ratings**

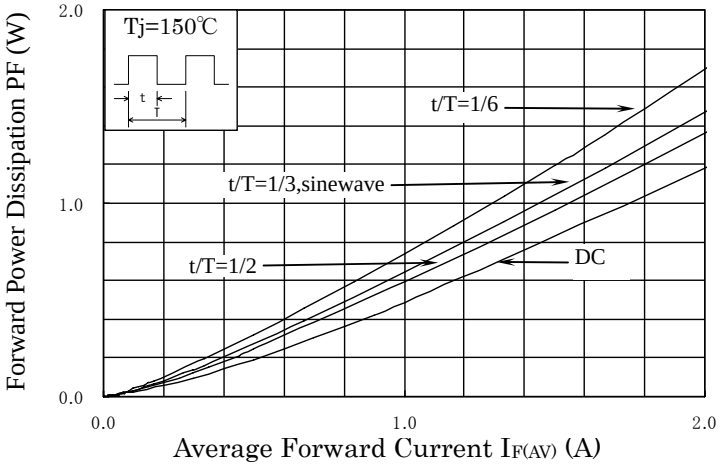
No.	Parameter	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	V_{RSM}	V	60	
2	Peak Reverse Voltage	V_{RM}	V	60	
3	Average Forward Current	$I_{F(AV)}$	A	2.0	
4	Peak Surge Forward Current	I_{FSM}	A	40	Half sinewave, one shot
5	I^2t Limiting Value	I^2t	A^2s	8.0	1msec<t<10msec
6	Junction Temperature	T_j	°C	-40 to +150	
7	Storage Temperature	T_{stg}	°C	-40 to +150	

✶ **Electrical characteristics (Ta=25°C, unless otherwise specified)**

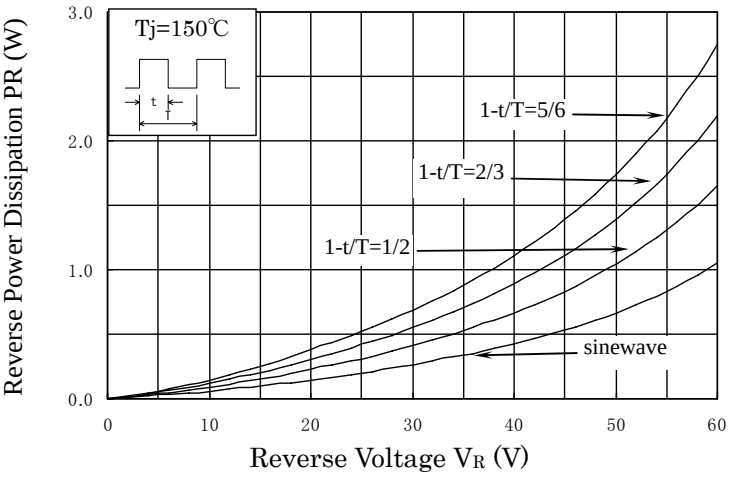
No.	Parameter	Symbol	Unit	Rating	Conditions
1	Forward Voltage Drop	V_F	V	0.69 max.	I_F=2.0A
2	Reverse Leakage Current	I_R	uA	200 max.	$V_R=V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H•I_R$	mA	55 max.	$V_R=V_{RM}$, T_j=150°C
4	Thermal Resistance	$R_{th(j-l)}$	°C/W	20 max.	Between Junction and Lead

✶ **Characteristics**

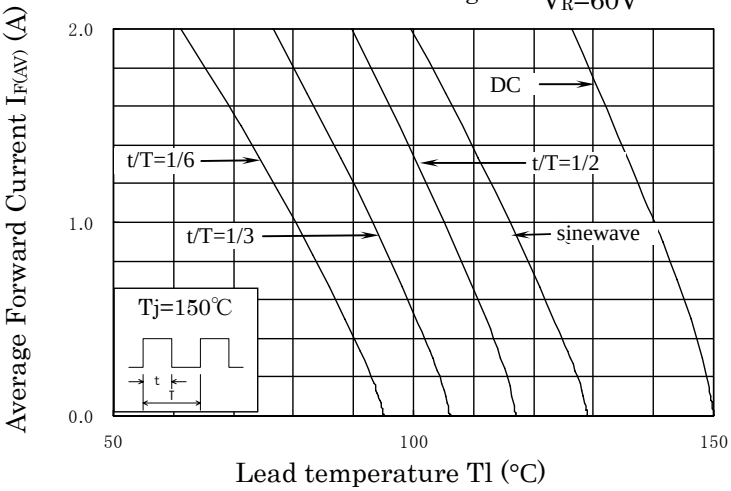
Forward Power Dissipation



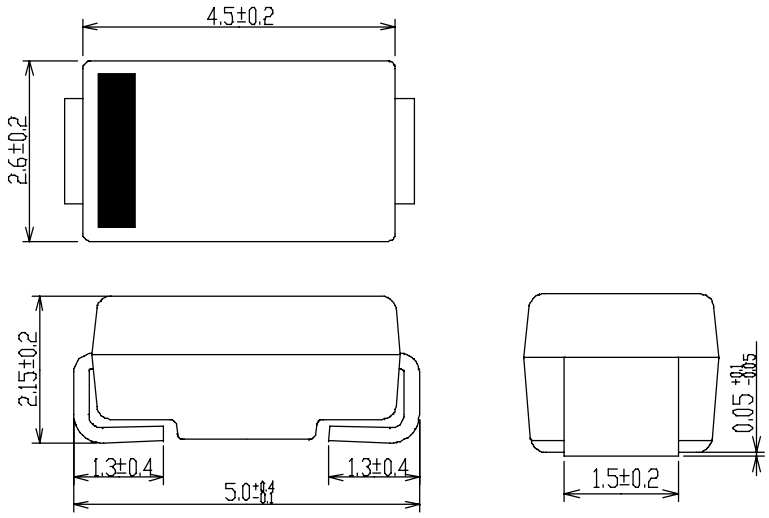
Reverse Power Dissipation



Current Derating VR=60V



✶ **Outline drawings, mm**



✶ **Connection Diagram**